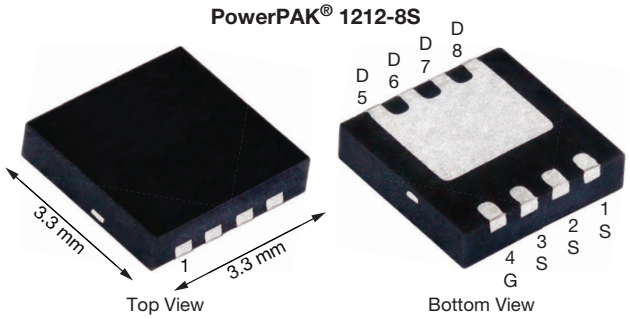
P-Channel 30 V (D-S) MOSFET

PRODUCT SUMMARY			
V_{DS} (V)	$R_{DS(on)}$ (Ω) MAX.	I_D (A)	Q_g (TYP.)
-30	0.0056 at V_{GS} = -10 V	-50 [e]	45 nC
	0.0070 at V_{GS} = -6 V	-50 [e]	
	0.0090 at V_{GS} = -4.5 V	-50 [e]	



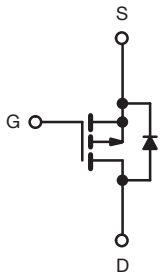
FEATURES

- TrenchFET® Power MOSFET
- Low thermal resistance PowerPAK® package with small size and low 0.75 mm profile
- 100 % R_g and UIS tested
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE

APPLICATIONS

- Notebook computers and mobile computing
  - Adaptor switch
  - Load switch
  - DC/DC converter
  - Power management



P-Channel MOSFET

Ordering Information:
SiSS27DN-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	-30	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current (T_J = 150 °C)	T_C = 25 °C	I_D	-50 [e]	A
	T_C = 70 °C		-50 [e]	
	T_A = 25 °C		-23 [a,b]	
	T_A = 70 °C		-18.5 [a,b]	
Pulsed Drain Current (t = 100 µs)		I_{DM}	-200	
Continuous Source-Drain Diode Current	T_C = 25 °C	I_S	-47.5	
	T_A = 25 °C		-4 [a,b]	
Avalanche Current	L = 0.1 mH	I_{AS}	-25	
Single-Pulse Avalanche Energy		E_{AS}	31	mJ
Maximum Power Dissipation	T_C = 25 °C	P_D	57	W
	T_C = 70 °C		36	
	T_A = 25 °C		4.8 [a,b]	
	T_A = 70 °C		3 [a,b]	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-50 to 150	°C
Soldering Recommendations (Peak Temperature) [c,d]			260	

Notes

a. Surface mounted on 1" x 1" FR4 board.
b. t = 10 s.
c. See solder profile (www.vishay.com/doc?73257). The PowerPAK 1212-8S is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
d. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.
e. Package limited.

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THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum Junction-to-Ambient [a,b]	t ≤ 10 s	R_{thJA}	21	26	°C/W
Maximum Junction-to-Case (Drain)	Steady State	R_{thJC}	1.7	2.2	

Notes

a. Surface mounted on 1" x 1" FR4 board.
b. Maximum under steady state conditions is 63 °C/W.

SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	V_{DS}	V_{GS} = 0 V, I_D = - 250 µA	-30	-	-	V
V_{DS} Temperature Coefficient	$\Delta V_{DS}/T_J$	I_D = -250 µA	-	-22	-	mV/°C
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$		-	5.7	-	
Gate-Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = -250 µA	-1	-	-2.2	V
Gate-Source Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	-	-	± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = -30 V, V_{GS} = 0 V	-	-	-1	µA
		V_{DS} = -30 V, V_{GS} = 0 V, T_J = 55 °C	-	-	-10	
On-State Drain Current [a]	$I_{D(on)}$	V_{DS} ≤ -5 V, V_{GS} = -10 V	-20	-	-	A
Drain-Source On-State Resistance [a]	$R_{DS(on)}$	V_{GS} = -10 V, I_D = -15 A	-	0.0046	0.0056	Ω
		V_{GS} = -6 V, I_D = -10 A	-	0.0058	0.0070	
		V_{GS} = -4.5 V, I_D = -5 A	-	0.0073	0.0090	
Forward Transconductance [a]	g_{fs}	V_{DS} = -15 V, I_D = -15 A	-	52	-	S
Dynamic [b]						
Input Capacitance	C_{iss}	V_{DS} = -15 V, V_{GS} = 0 V, f = 1 MHz	-	5250	-	pF
Output Capacitance	C_{oss}		-	530	-	
Reverse Transfer Capacitance	C_{rss}		-	485	-	
Total Gate Charge	Q_g	V_{DS} = -15 V, V_{GS} = -10 V, I_D = -20 A	-	92	140	nC
		V_{DS} = -15 V, V_{GS} = -4.5 V, I_D = -20 A	-	45	70	
Gate-Source Charge	Q_{gs}		-	15	-	
Gate-Drain Charge	Q_{gd}		-	16	-	
Gate Resistance	R_g	f = 1 MHz	0.6	3	6	Ω
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = -15 V, R_L = 1.5 Ω I_D ≅ -10 A, V_{GEN} = -4.5 V, R_g = 1 Ω	-	60	120	ns
Rise Time	t_r		-	45	90	
Turn-Off DelayTime	$t_{d(off)}$		-	50	100	
Fall Time	t_f		-	20	40	
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = -15 V, R_L = 1.5 Ω I_D ≅ -10 A, V_{GEN} = -10 V, R_g = 1 Ω	-	16	30	
Rise Time	t_r		-	5	10	
Turn-Off DelayTime	$t_{d(off)}$		-	65	130	
Fall Time	t_f		-	10	20	
Drain-Source Body Diode Characteristics						
Continuous Source-Drain Diode Current	I_S	T_C = 25 °C	-	-	-50 [c]	A
Pulse Diode Forward Current [d]	I_{SM}		-	-	-200	
Body Diode Voltage	V_{SD}	I_F = -10 A	-	-0.8	-1.2	V
Body Diode Reverse Recovery Time	t_{rr}	I_F = -10 A, dI/dt = 100 A/µs, T_J = 25 °C	-	30	60	ns
Body Diode Reverse Recovery Charge	Q_{rr}		-	21	40	nC
Reverse Recovery Fall Time	t_a		-	16	-	ns
Reverse Recovery Rise Time	t_b		-	14	-	

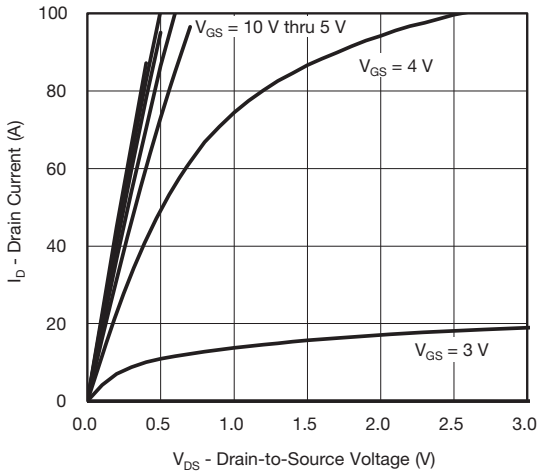
Notes

a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.
c. Package limited.
d. t = 100 µs.

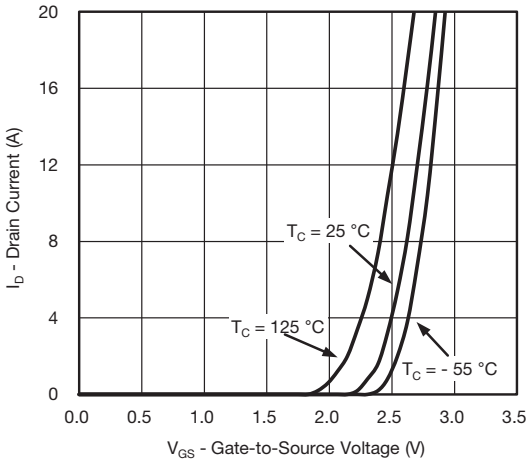
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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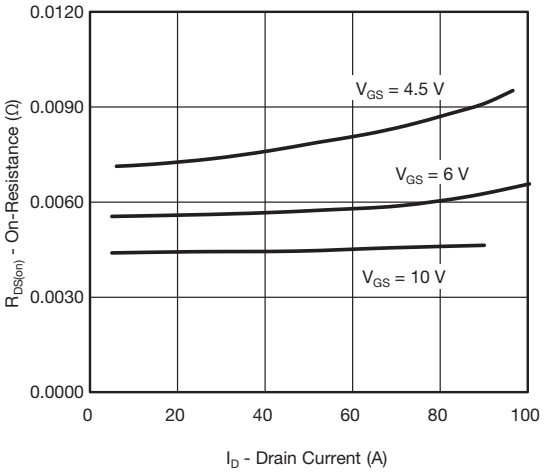
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



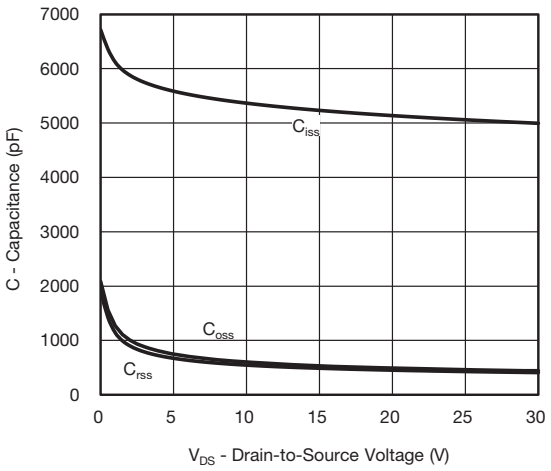
Output Characteristics



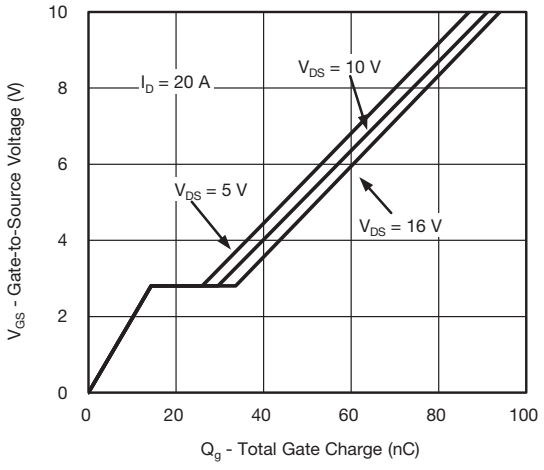
Transfer Characteristics



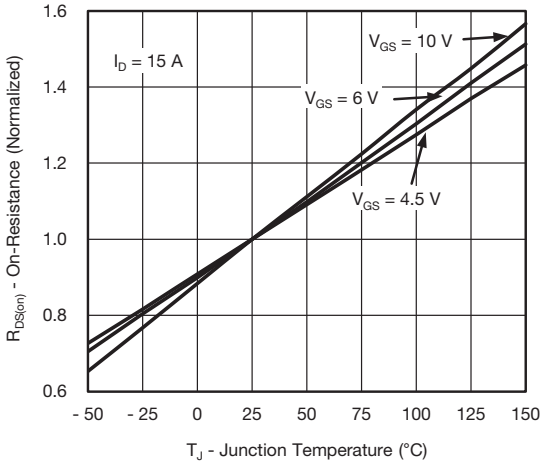
On-Resistance vs. Drain Current and Gate Voltage



Capacitance



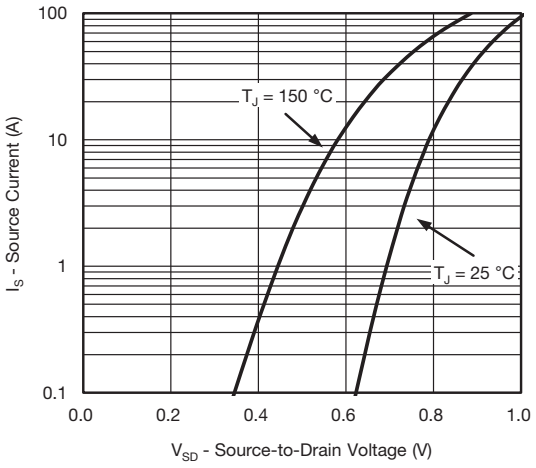
Gate Charge



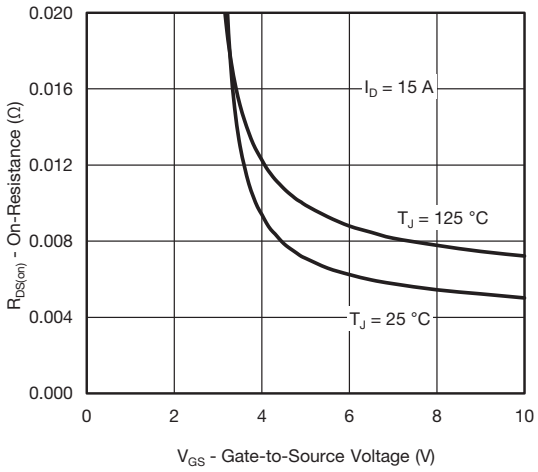
On-Resistance vs. Junction Temperature

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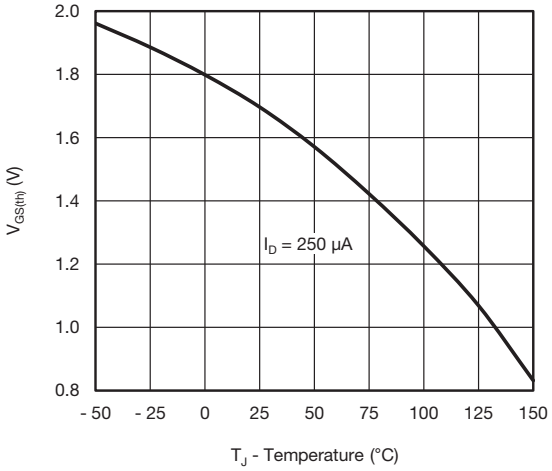
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



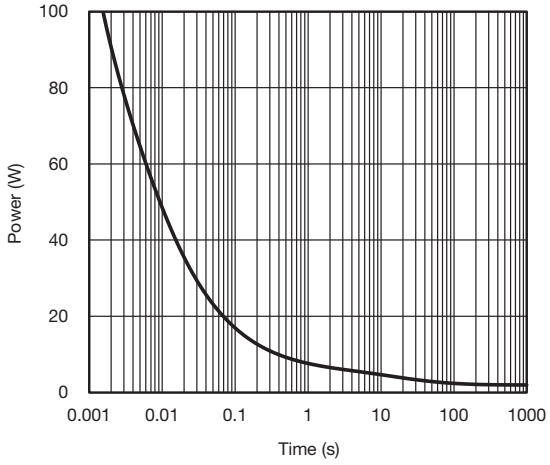
Source-Drain Diode Forward Voltage



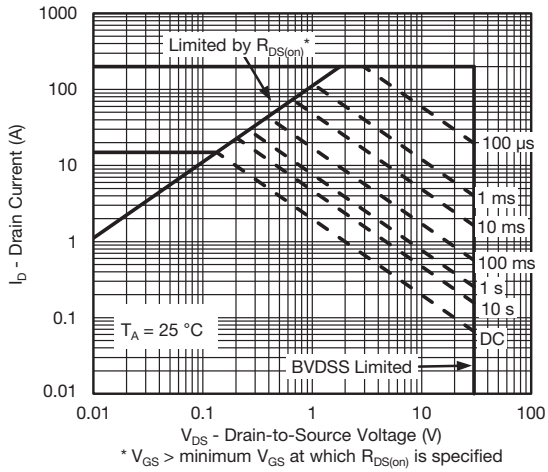
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



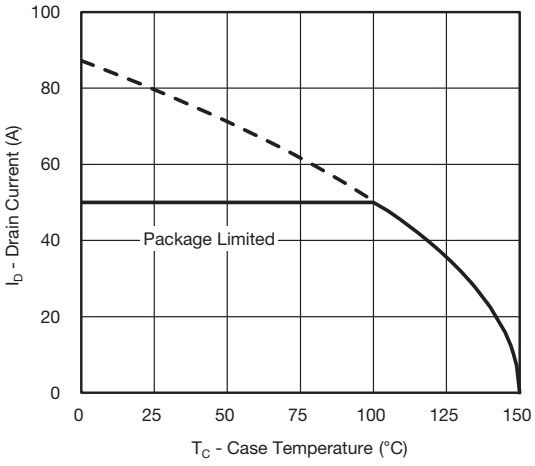
Single Pulse Power, Junction-to-Ambient



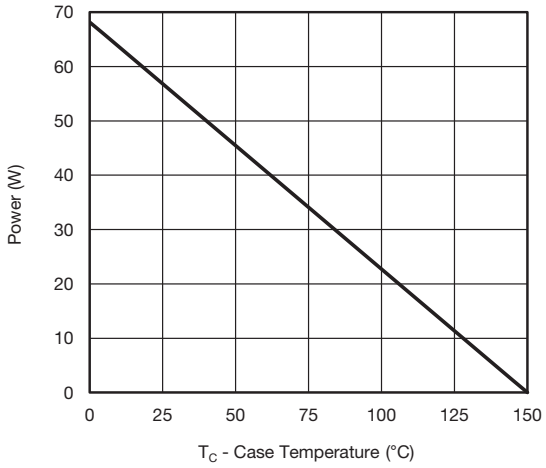
Safe Operating Area, Junction-to-Ambient

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating*

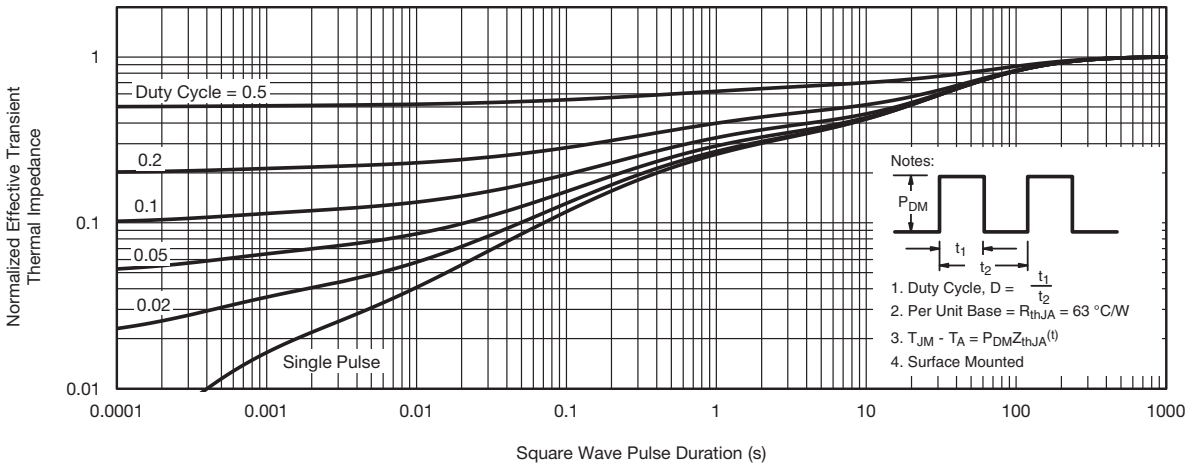


Power, Junction-to-Case

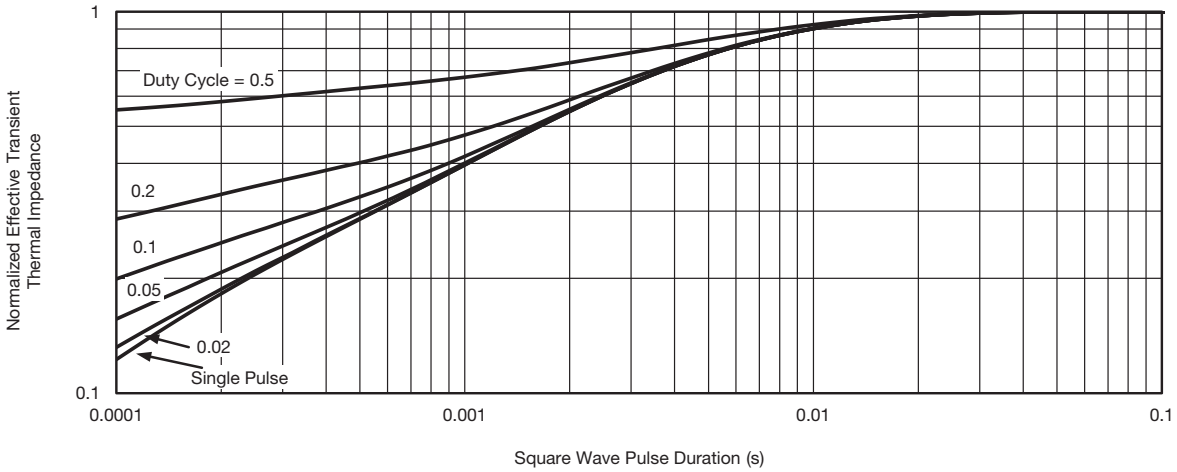
* The power dissipation P_D is based on $T_{J(max.)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

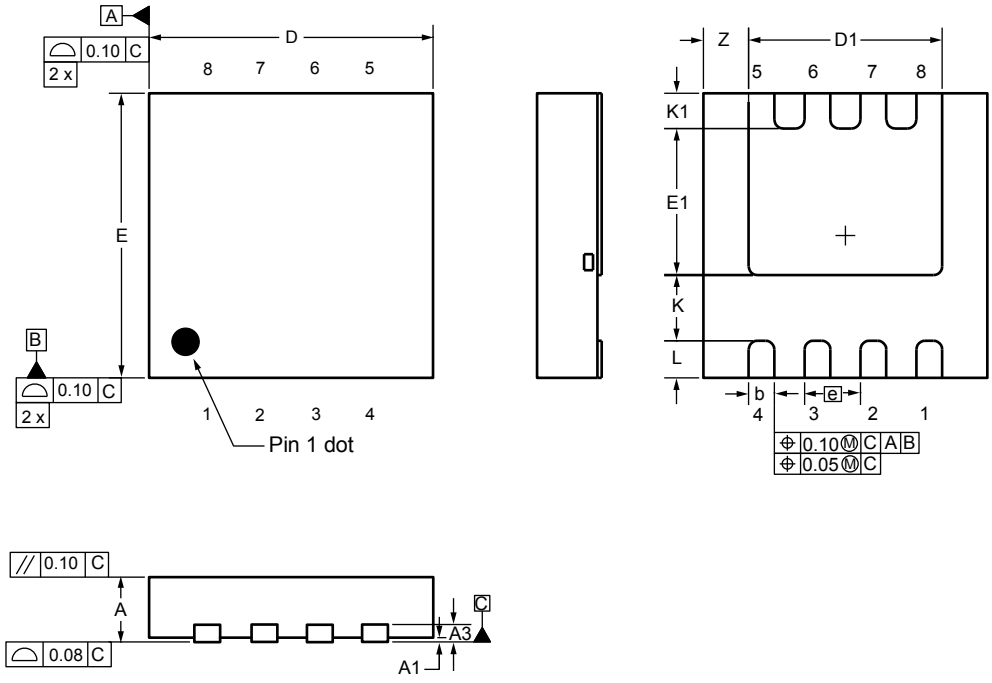


Normalized Thermal Transient Impedance, Junction-to-Case

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Case Outline for PowerPAK® 1212-8S



DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.67	0.75	0.83	0.026	0.030	0.033
A1	0.00	-	0.05	0.000	-	0.002
A3	0.20 ref.			0.008 ref		
b	0.25	0.30	0.35	0.010	0.012	0.014
D	3.20	3.30	3.40	0.126	0.130	0.134
D1	2.15	2.25	2.35	0.085	0.089	0.093
E	3.20	3.30	3.40	0.126	0.130	0.134
E1	1.60	1.70	1.80	0.063	0.067	0.071
e	0.65 bsc.			0.026 bsc.		
K	0.76 ref.			0.030 ref.		
K1	0.41 ref.			0.016 ref.		
L	0.33	0.43	0.53	0.013	0.017	0.021
Z	0.525 ref.			0.021 ref.		
ECN: C20-0862-Rev. B, 20-Jul-2020 DWG: 6008						

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